## / Descriptions

SOT23-3 ĮĮĿ S ŏ MOS ĵ ŵ Ż ˥

P- CHANNEL MOSFET in a SOT23-3 Plastic Package.

## / Features

$V_{DS}$ (V)=-20V $I_D$ =-5.0A($V_{GS}$= ± 10V)

$R_{DS(ON)}$< 40 mΩ,$V_{GS}$= -4.5V

$R_{DS(ON)}$< 53 mΩ,$V_{GS}$= -2.5V

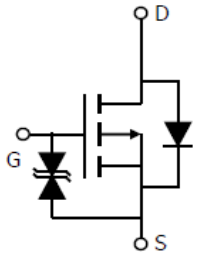
ŋ ŧ β HF Product.

## / Applications

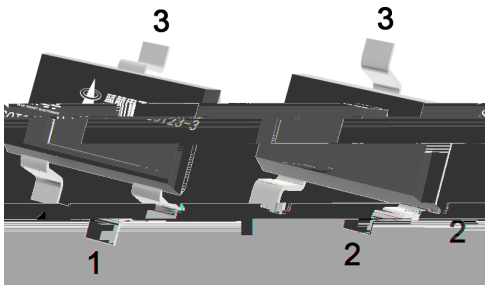
ق ŏ Ầ ћ ı ɔ – Ȝ ĭ

Load switch ı Battery protection.

## / Equivalent Circuit




## / Pinning




PIN1 χ G PIN 2 χ S PIN 3 χ D

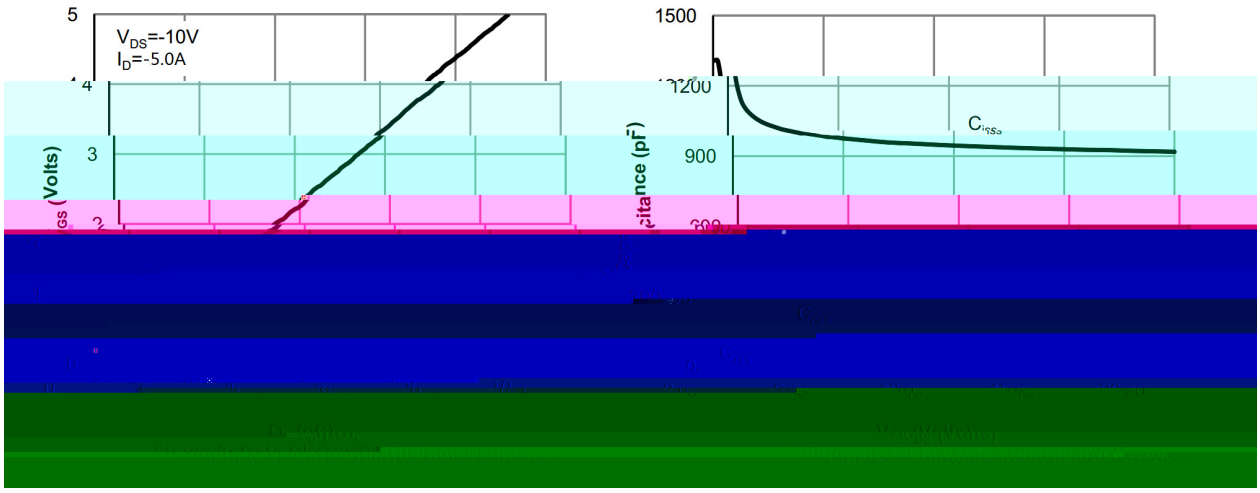
## / Marking

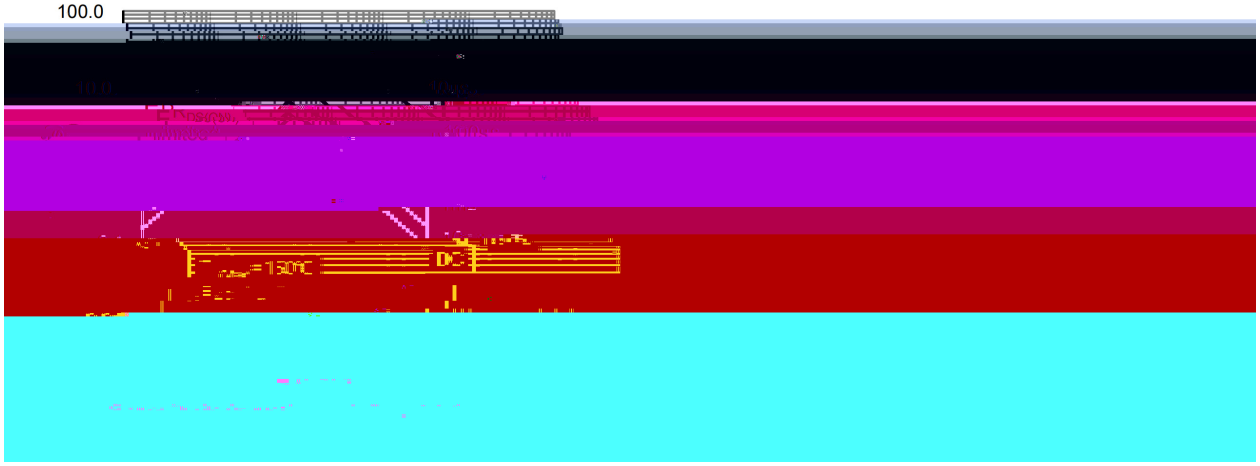
| | |
|---|---|
| Marking | AFH |

| v ̈Ω<br>Parameter | ϒ N<br>Symbol | ̈Ω Ö<br>Rating | D Ꮋ<br>Unit |
|---|---|---|---|
| Drain-Source Voltage | $V_{DS}$ | -20 | V |
| Gate-Source Voltage | $V_{GS}$ | ± 10 | V |
| Drain Current-Continuous | $I_D$ | -5.0 | A |
| Drain Current-Pulsed | $I_{DM}$ | | |

## / Electrical Characteristic Curve

## / Electrical Characteristic Curve



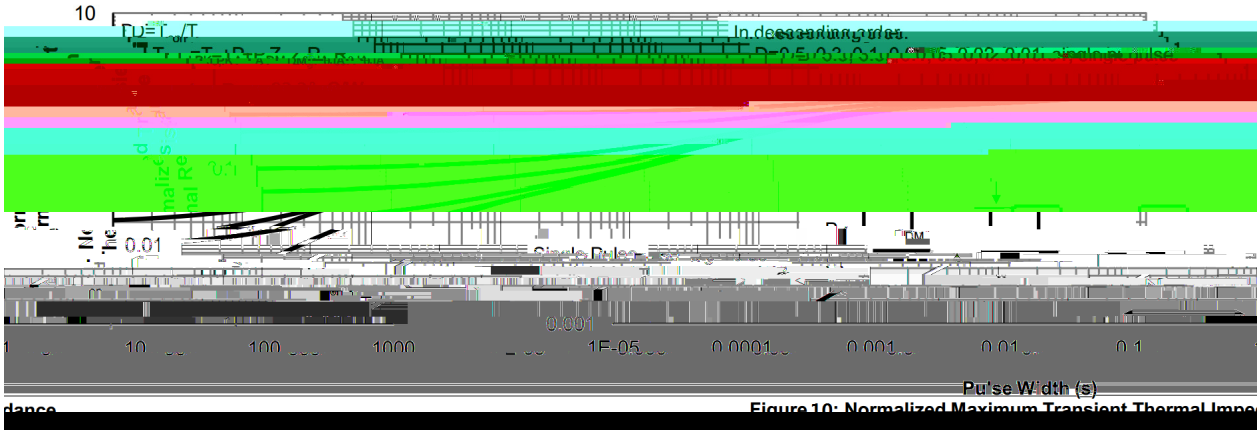
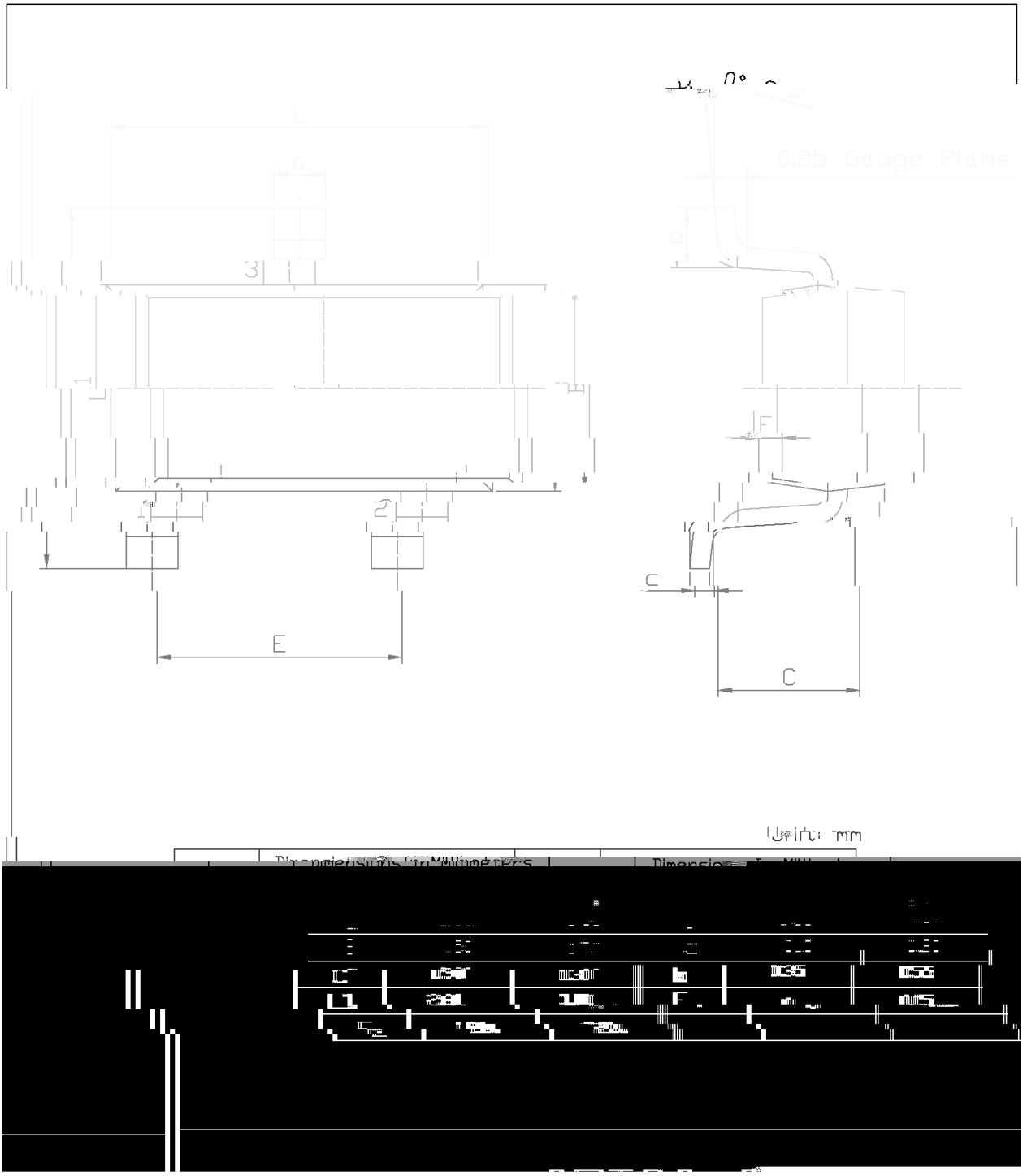
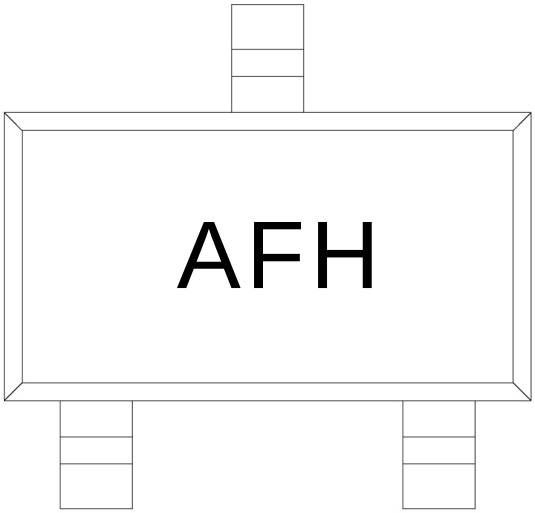




Figure 10: Normalized Maximum Transient Thermal Impe

## / Package Dimensions



## / Marking Instructions




ᴗ ˝ χ

H: ᵻᵡ ϛ ᵢᴵ ᴨ

AF: ᵻᵡ ʒ ᴺ ᴨ

Note:

H: Company Code

AF χ Product Type Code

## ( ) / Temperature Profile for IR Reflow Soldering(Pb-Free)



ب ˝ χ

1 Ĺ ♬ □ ў 150 Ќ 180 ћ ı `H ђ 60 Ќ 90sec;

2 Š Ө □ ў 245 ° 5 ћ ı `H ђ `Y ѓ ѭ 5 ° 0.5sec;

3 ì ˙ ٧ ˛ ɔ ѕ ў ѭ 2 Ќ 10 ћ /sec.

Note:

1.Preheating:150~180 ћ , Time:60~90sec.

2.Peak Temp.:245 ° 5 ћ , Duration:5 ° 0.5sec.

3. Cooling Speed: 2~10 ћ /sec.

## / Resistance to Soldering Heat Test Conditions

| | | | |
|---|---|---|---|
| □ ў χ 260 ° 5 ћ | `H ђ χ 10 ° 1 sec. | Temp.:260±5 | Time:10±1 sec |

## / Packaging SPEC.

ɔ ` ɣ Ь / REEL

Package Type Units Dimension (unit mm 3]Q9ZH)